

# Thyristor \ Diode Module

$V_{RRM} = 2 \times 1600 \text{ V}$

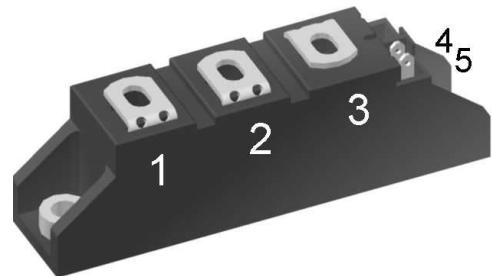
$I_{TAV} = 50 \text{ A}$

$V_T = 1.17 \text{ V}$

## Phase leg

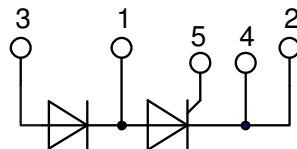
### Part number

MCMA50PD1600TB



Backside: isolated

 E72873



### Features / Advantages:

- Thyristor for line frequency
- Planar passivated chip
- Long-term stability
- Direct Copper Bonded Al2O3-ceramic

### Applications:

- Line rectifying 50/60 Hz
- Softstart AC motor control
- DC Motor control
- Power converter
- AC power control
- Lighting and temperature control

### Package: TO-240AA

- Isolation Voltage: 4800 V~
- Industry standard outline
- RoHS compliant
- Soldering pins for PCB mounting
- Base plate: DCB ceramic
- Reduced weight
- Advanced power cycling

### Terms & Conditions of usage:

The data contained in this product data sheet is exclusively intended for technically trained staff. The user will have to evaluate the suitability of the product for the intended application and the completeness of the product data with respect to his application. The specifications of our components may not be considered as an assurance of component characteristics. The information in the valid application- and assembly notes must be considered. Should you require product information in excess of the data given in this product data sheet or which concerns the specific application of your product, please contact your local sales office.

Due to technical requirements our product may contain dangerous substances. For information on the types in question please contact your local sales office.

Should you intend to use the product in aviation, in health or life endangering or life support applications, please notify. For any such application we urgently recommend

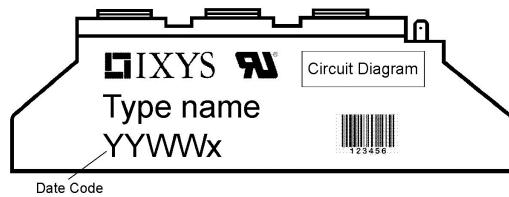
- to perform joint risk and quality assessments;

- the conclusion of quality agreements;

- to establish joint measures of an ongoing product survey, and that we may make delivery dependent on the realization of any such measures.

Rectifier			Ratings			
Symbol	Definition	Conditions	min.	typ.	max.	Unit
$V_{RSM/DSM}$	max. non-repetitive reverse/forward blocking voltage	$T_{VJ} = 25^\circ C$			1700	V
$V_{RRM/DRM}$	max. repetitive reverse/forward blocking voltage	$T_{VJ} = 25^\circ C$			1600	V
$I_{R/D}$	reverse current, drain current	$V_{R/D} = 1600 V$ $V_{R/D} = 1600 V$	$T_{VJ} = 25^\circ C$ $T_{VJ} = 140^\circ C$		100 6	$\mu A$ mA
$V_T$	forward voltage drop	$I_T = 50 A$	$T_{VJ} = 25^\circ C$		1.25	V
		$I_T = 100 A$			1.48	V
		$I_T = 50 A$ $I_T = 100 A$	$T_{VJ} = 125^\circ C$		1.17 1.44	V
$I_{TAV}$	average forward current	$T_C = 85^\circ C$	$T_{VJ} = 140^\circ C$		50	A
$I_{T(RMS)}$	RMS forward current	180° sine			79	A
$V_{T0}$	threshold voltage	$r_T$ slope resistance } for power loss calculation only	$T_{VJ} = 140^\circ C$		0.89	V
					5.3	$m\Omega$
$R_{thJC}$	thermal resistance junction to case				0.7	K/W
$R_{thCH}$	thermal resistance case to heatsink			0.20		K/W
$P_{tot}$	total power dissipation		$T_C = 25^\circ C$		160	W
$I_{TSM}$	max. forward surge current	$t = 10 \text{ ms}; (50 \text{ Hz}), \text{sine}$	$T_{VJ} = 45^\circ C$		800	A
		$t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{sine}$	$V_R = 0 V$		865	A
		$t = 10 \text{ ms}; (50 \text{ Hz}), \text{sine}$	$T_{VJ} = 140^\circ C$		680	A
		$t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{sine}$	$V_R = 0 V$		735	A
$I^2t$	value for fusing	$t = 10 \text{ ms}; (50 \text{ Hz}), \text{sine}$	$T_{VJ} = 45^\circ C$		3.20	$kA^2s$
		$t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{sine}$	$V_R = 0 V$		3.12	$kA^2s$
		$t = 10 \text{ ms}; (50 \text{ Hz}), \text{sine}$	$T_{VJ} = 140^\circ C$		2.31	$kA^2s$
		$t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{sine}$	$V_R = 0 V$		2.25	$kA^2s$
$C_J$	junction capacitance	$V_R = 400 V$ $f = 1 \text{ MHz}$	$T_{VJ} = 25^\circ C$	32		pF
$P_{GM}$	max. gate power dissipation	$t_p = 30 \mu s$	$T_C = 140^\circ C$		10	W
		$t_p = 300 \mu s$			5	W
$P_{GAV}$	average gate power dissipation				0.5	W
$(di/dt)_{cr}$	critical rate of rise of current	$T_{VJ} = 140^\circ C; f = 50 \text{ Hz}$ repetitive, $I_T = 150 A$			150	$A/\mu s$
		$t_p = 200 \mu s; di_G/dt = 0.45 A/\mu s$				
		$I_G = 0.45 A; V = \frac{2}{3} V_{DRM}$ non-repet., $I_T = 50 A$			500	$A/\mu s$
$(dv/dt)_{cr}$	critical rate of rise of voltage	$V = \frac{2}{3} V_{DRM}$	$T_{VJ} = 140^\circ C$		1000	$V/\mu s$
		$R_{GK} = \infty$ ; method 1 (linear voltage rise)				
$V_{GT}$	gate trigger voltage	$V_D = 6 V$	$T_{VJ} = 25^\circ C$		1.5	V
			$T_{VJ} = -40^\circ C$		1.6	V
$I_{GT}$	gate trigger current	$V_D = 6 V$	$T_{VJ} = 25^\circ C$		78	mA
			$T_{VJ} = -40^\circ C$		200	mA
$V_{GD}$	gate non-trigger voltage	$V_D = \frac{2}{3} V_{DRM}$	$T_{VJ} = 140^\circ C$		0.2	V
$I_{GD}$	gate non-trigger current				5	mA
$I_L$	latching current	$t_p = 10 \mu s$ $I_G = 0.45 A; di_G/dt = 0.45 A/\mu s$	$T_{VJ} = 25^\circ C$		200	mA
$I_H$	holding current	$V_D = 6 V$ $R_{GK} = \infty$	$T_{VJ} = 25^\circ C$		100	mA
$t_{gd}$	gate controlled delay time	$V_D = \frac{1}{2} V_{DRM}$	$T_{VJ} = 25^\circ C$		2	$\mu s$
		$I_G = 0.45 A; di_G/dt = 0.45 A/\mu s$				
$t_q$	turn-off time	$V_R = 100 V; I_T = 50 A; V = \frac{2}{3} V_{DRM}$ $T_{VJ} = 125^\circ C$ $di/dt = 10 A/\mu s$ $dv/dt = 20 V/\mu s$ $t_p = 200 \mu s$		150		$\mu s$

Package TO-240AA			Ratings			
Symbol	Definition	Conditions	min.	typ.	max.	Unit
$I_{RMS}$	$RMS$ current	per terminal			100	A
$T_{VJ}$	virtual junction temperature		-40		140	°C
$T_{op}$	operation temperature		-40		125	°C
$T_{stg}$	storage temperature		-40		125	°C
<b>Weight</b>				81		g
$M_D$	mounting torque		2.5		4	Nm
$M_T$	terminal torque		2.5		4	Nm
$d_{Spp/App}$	creepage distance on surface / striking distance through air		terminal to terminal	13.0	9.7	mm
$d_{Spb/Abp}$			terminal to backside	16.0	16.0	mm
$V_{ISOL}$	isolation voltage	$t = 1$ second $t = 1$ minute	50/60 Hz, RMS; $I_{ISOL} \leq 1$ mA		4800 4000	V V



#### Part description

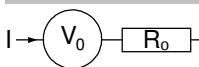
M = Module  
 C = Thyristor (SCR)  
 M = Thyristor  
 A = (up to 1800V)  
 50 = Current Rating [A]  
 PD = Phase leg  
 1600 = Reverse Voltage [V]  
 TB = TO-240AA-1B

Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	MCMA50PD1600TB	MCMA50PD1600TB	Box	36	515028

#### Equivalent Circuits for Simulation

\* on die level

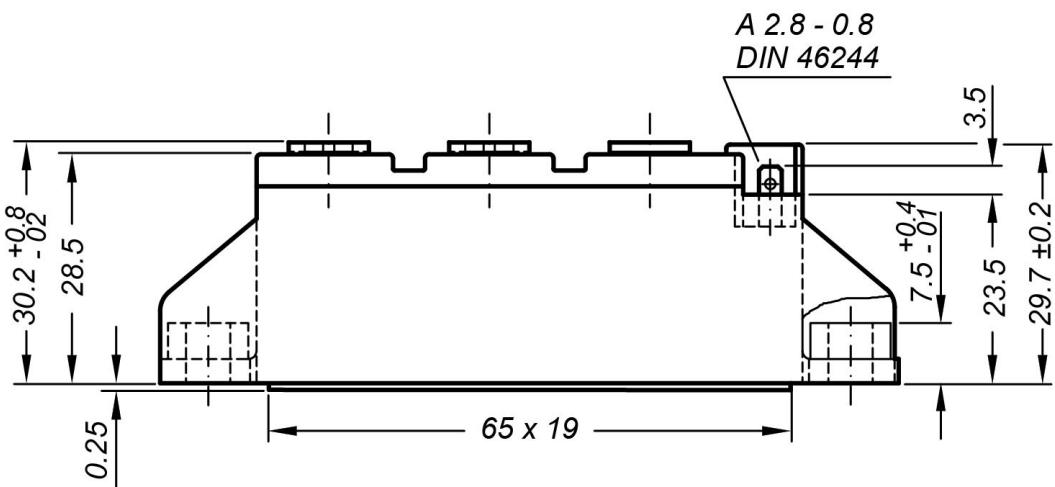
$T_{VJ} = 140$  °C



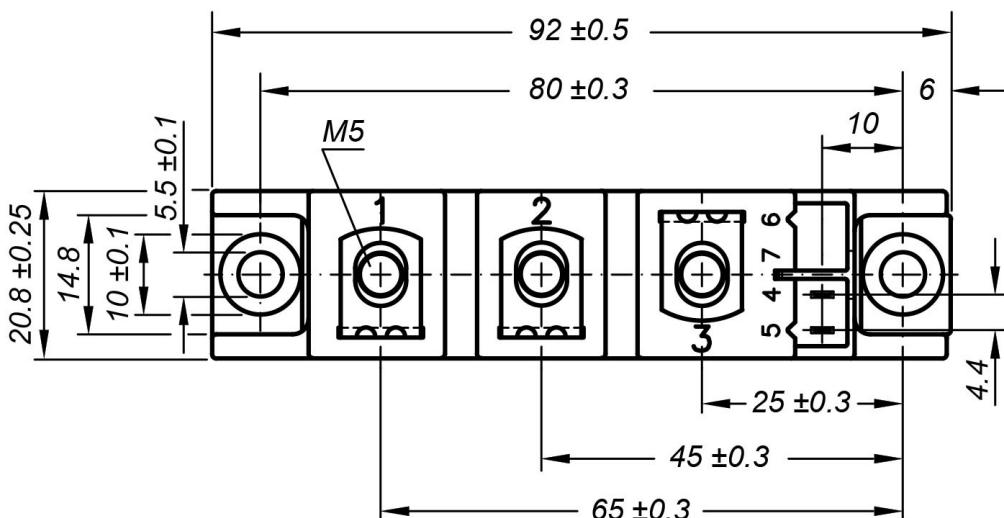
Thyristor

$V_{0\max}$  threshold voltage 0.89 V  
 $R_{0\max}$  slope resistance \* 4.1 mΩ

## Outlines TO-240AA



General tolerance: DIN ISO 2768 class „c“

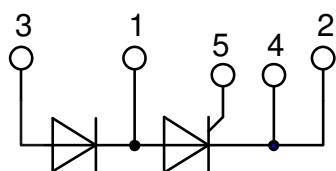


Optional accessories: Keyed gate/cathode twin plugs

Wire length: 350 mm, gate = white, cathode = red

UL 758, style 3751

Type **ZY 200L** (L = Left for pin pair 4/5)



## Thyristor

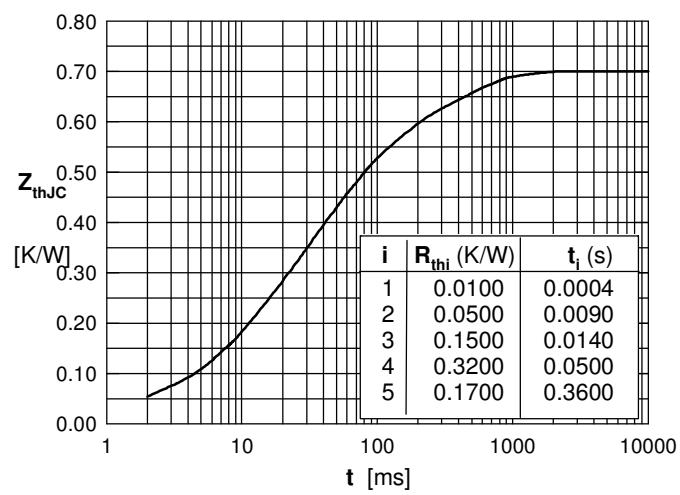
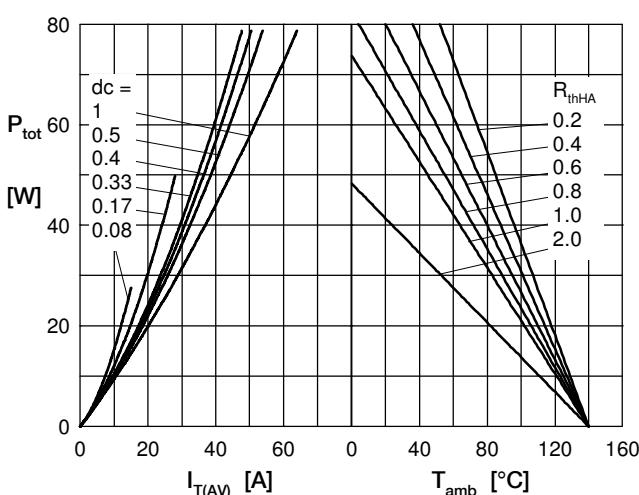
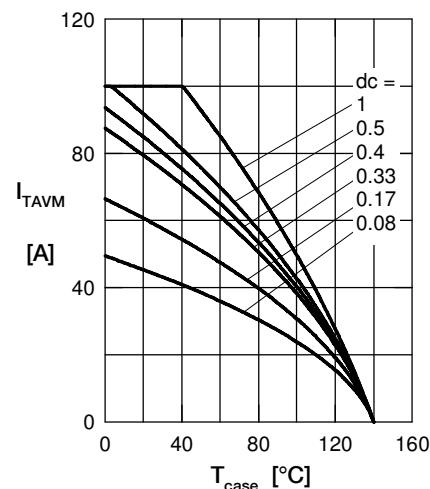
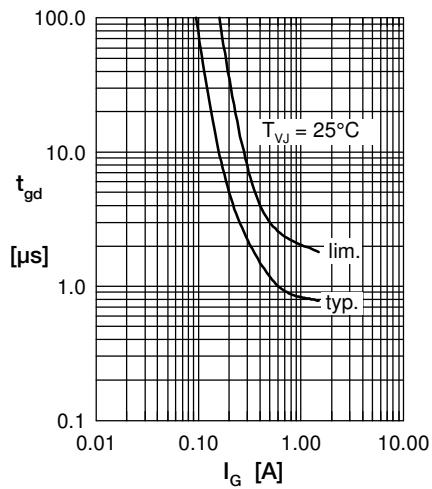
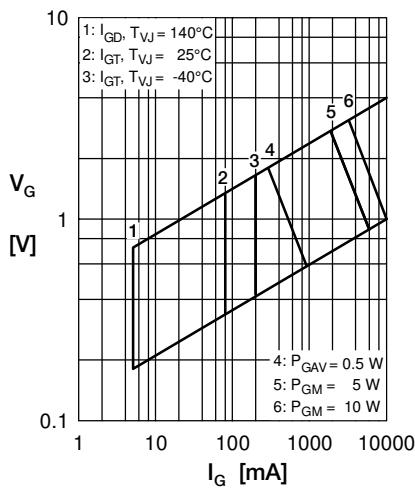
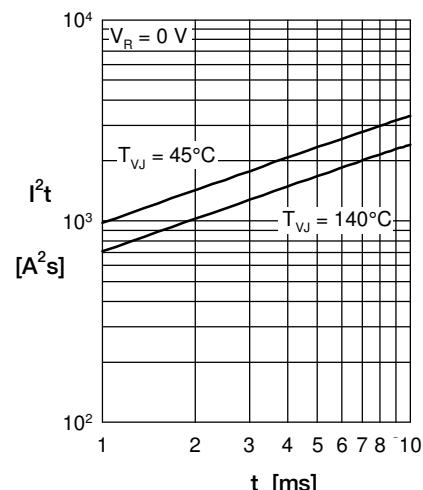
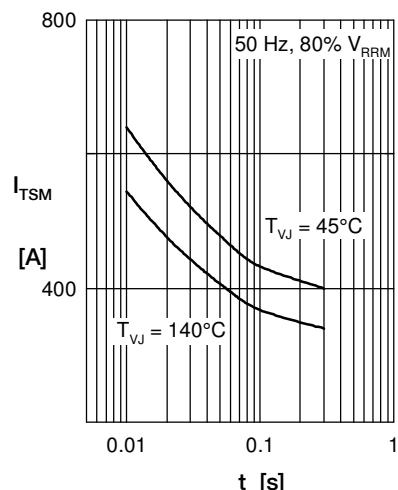
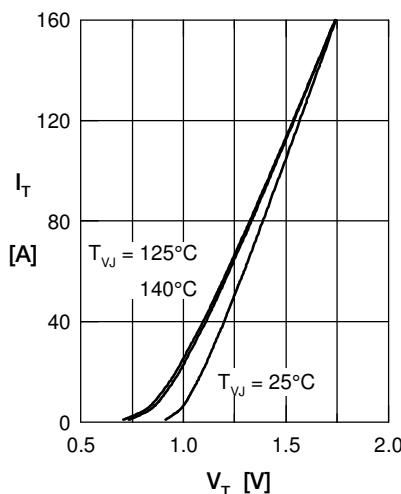


Fig. 7b and ambient temperature

Fig. 8 Transient thermal impedance junction to case

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